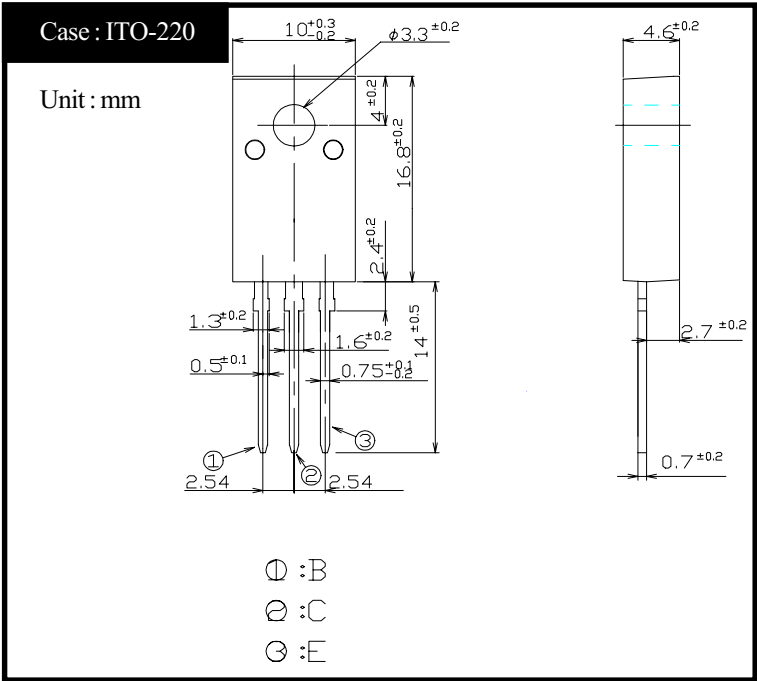


Darlington Transistor

2SD1795
(TP10K40)

10A NPN

OUTLINE DIMENSIONS



RATINGS

● Absolute Maximum Ratings

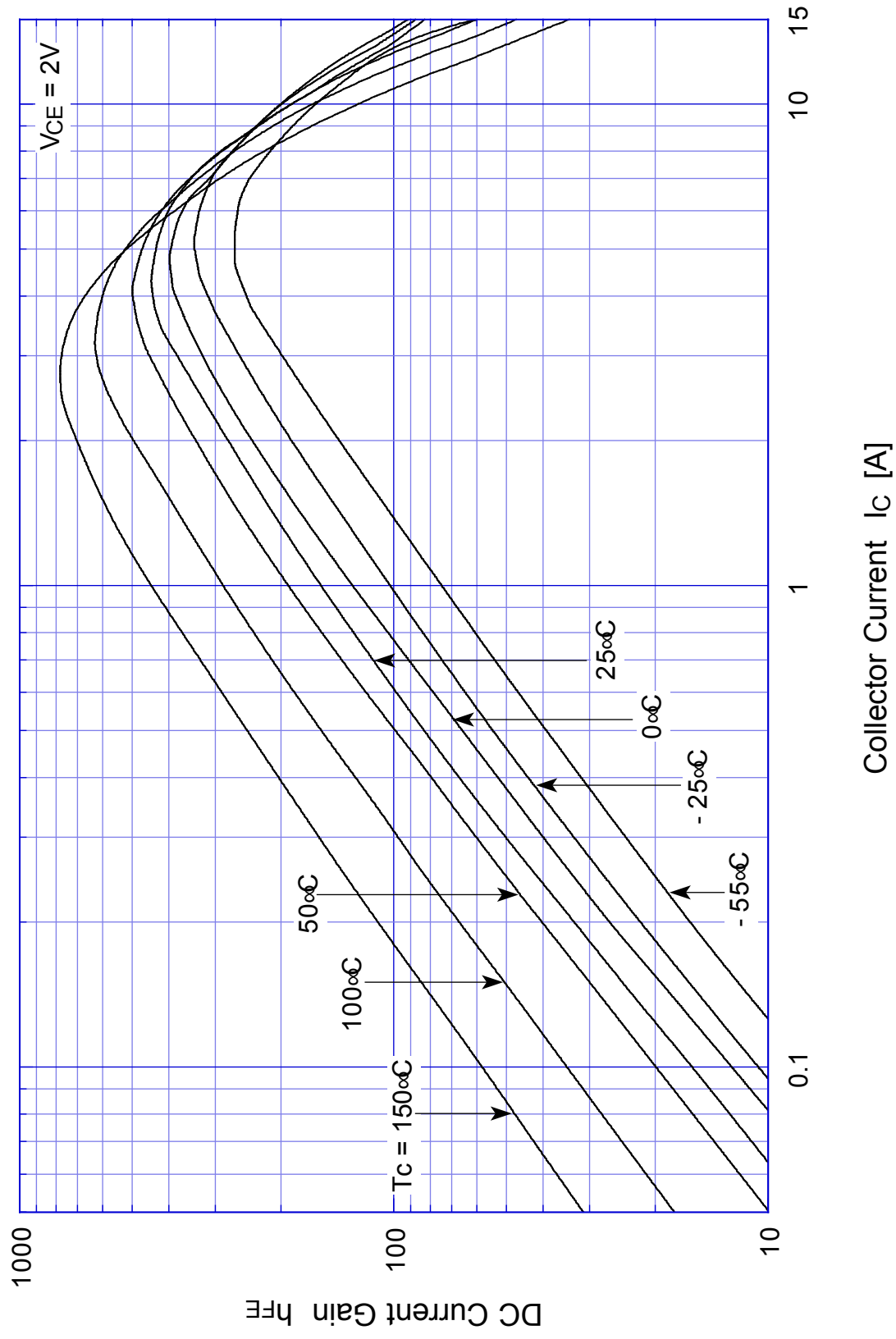
Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T _{stg}		-55~+150	°C
Junction Temperature	T _j		+150	°C
Collector to Base Voltage	V _{CBO}		500	V
Collector to Emitter Voltage	V _{CEO}		400	V
Emitter to Base Voltage	V _{EBO}		12	V
Collector Current DC	I _C		10	A
Collector Current Peak	I _{CP}		15	A
Base Current DC	I _B		0.5	A
Base Current Peak	I _{BP}		1.0	A
Total Transistor Dissipation	P _T	T _c = 25°C	50	W
Dielectric Strength	V _{dis}	Terminals to case AC 1 minute	2	kV
Mounting Torque	TOR	(Recommended torque : 0.3N·m)	0.5	N·m

● Electrical Characteristics (T_c=25°C)

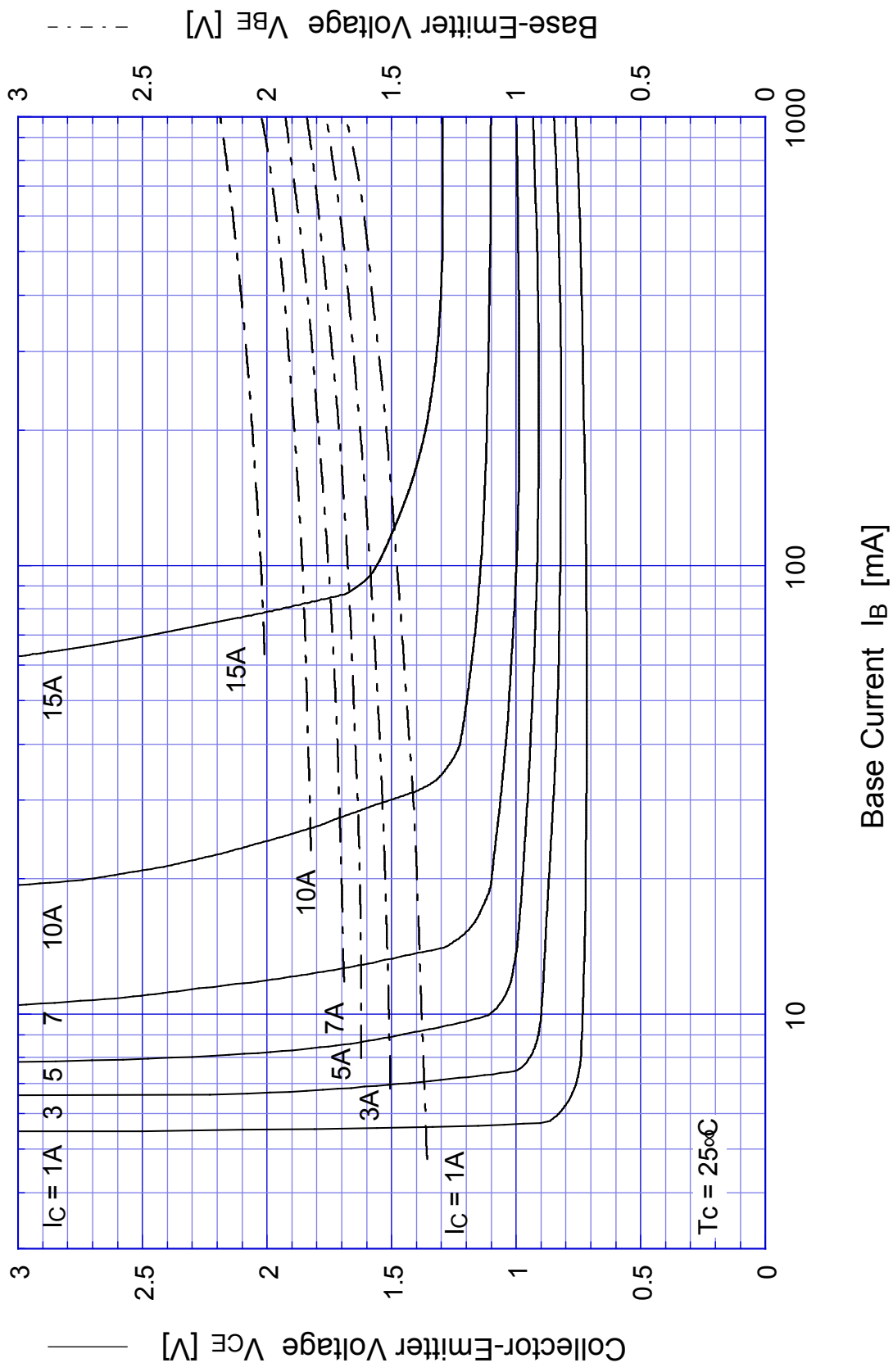
Item	Symbol	Conditions	Ratings	Unit
Collector to Emitter Sustaining Voltage	V _{CEO}	V _{CE} (Clamp)	Min 400	V
Collector Cutoff Current	I _{CBO}	V _{CB} = 500V	Max 0.1	mA
	I _{CEO}	V _{CE} = 400V	Max 0.1	
Emitter Cutoff Current	I _{EBO}	V _{EB} = 12V	Max 100	mA
DC Current Gain	h _{FE}	V _{CE} = 2V, I _C = 7A	Min 150	
Collector to Emitter Saturation Voltage	V _{CE(sat)}	I _C = 7A	Max 1.5	V
Base to Emitter Saturation Voltage	V _{BE(sat)}	I _B = 70mA	Max 2.0	V
Thermal Resistance	θ _{jc}	Junction to case	Max 2.5	°C/W
Transition Frequency	f _T	V _{CE} = 10V, I _C = 1A	TYP 10	MHz
Turn on Time	ton	I _C = 7A I _{B1} = I _{B2} = 70mA R _L = 10 Ω V _{BB2} = 4V	Max 2	μ s
Storage Time	ts		Max 15	
Fall Time	tf		Max 15	

2SD1795

$h_{FE} - I_C$

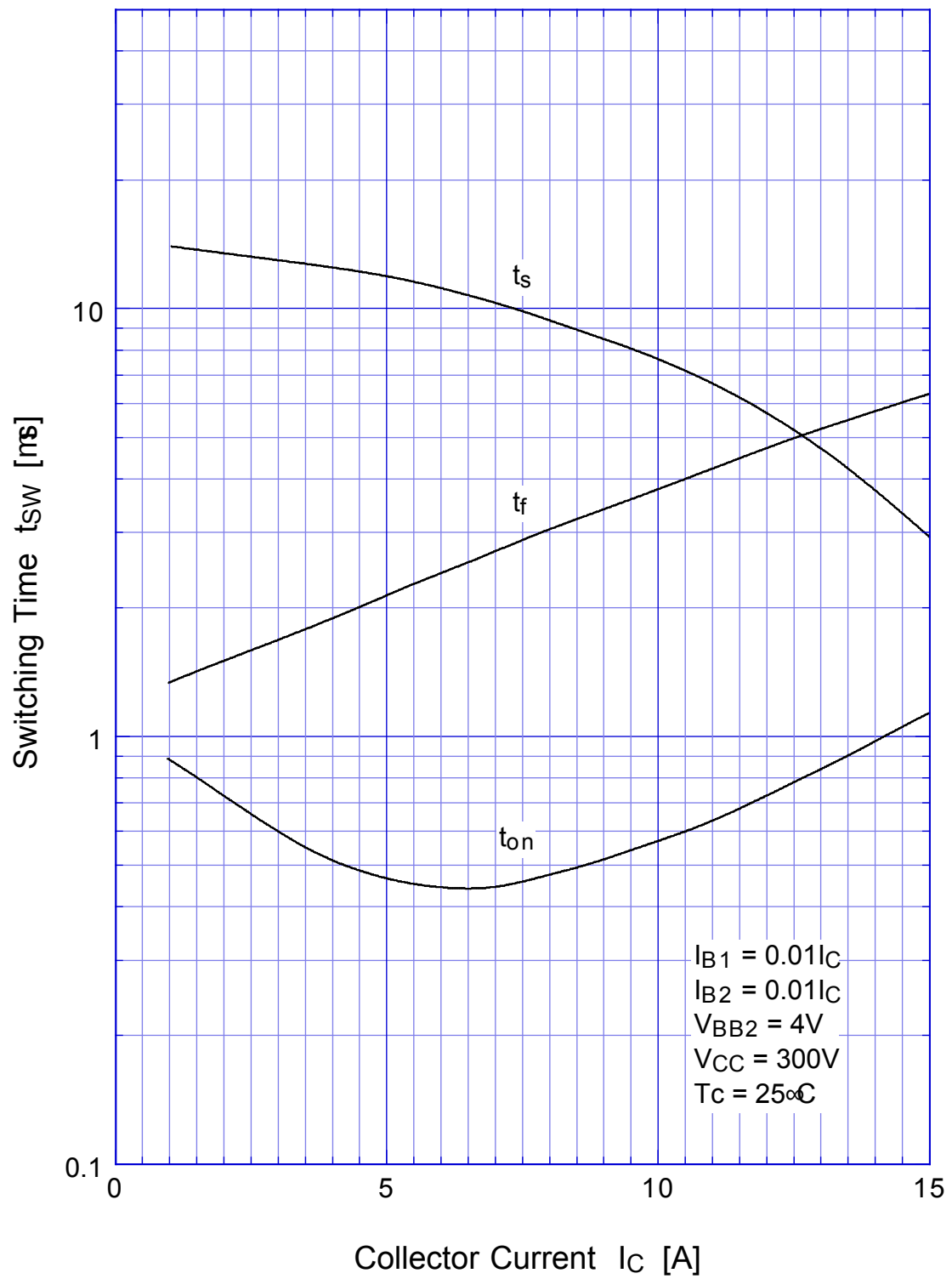


2SD1795 Saturation Voltage



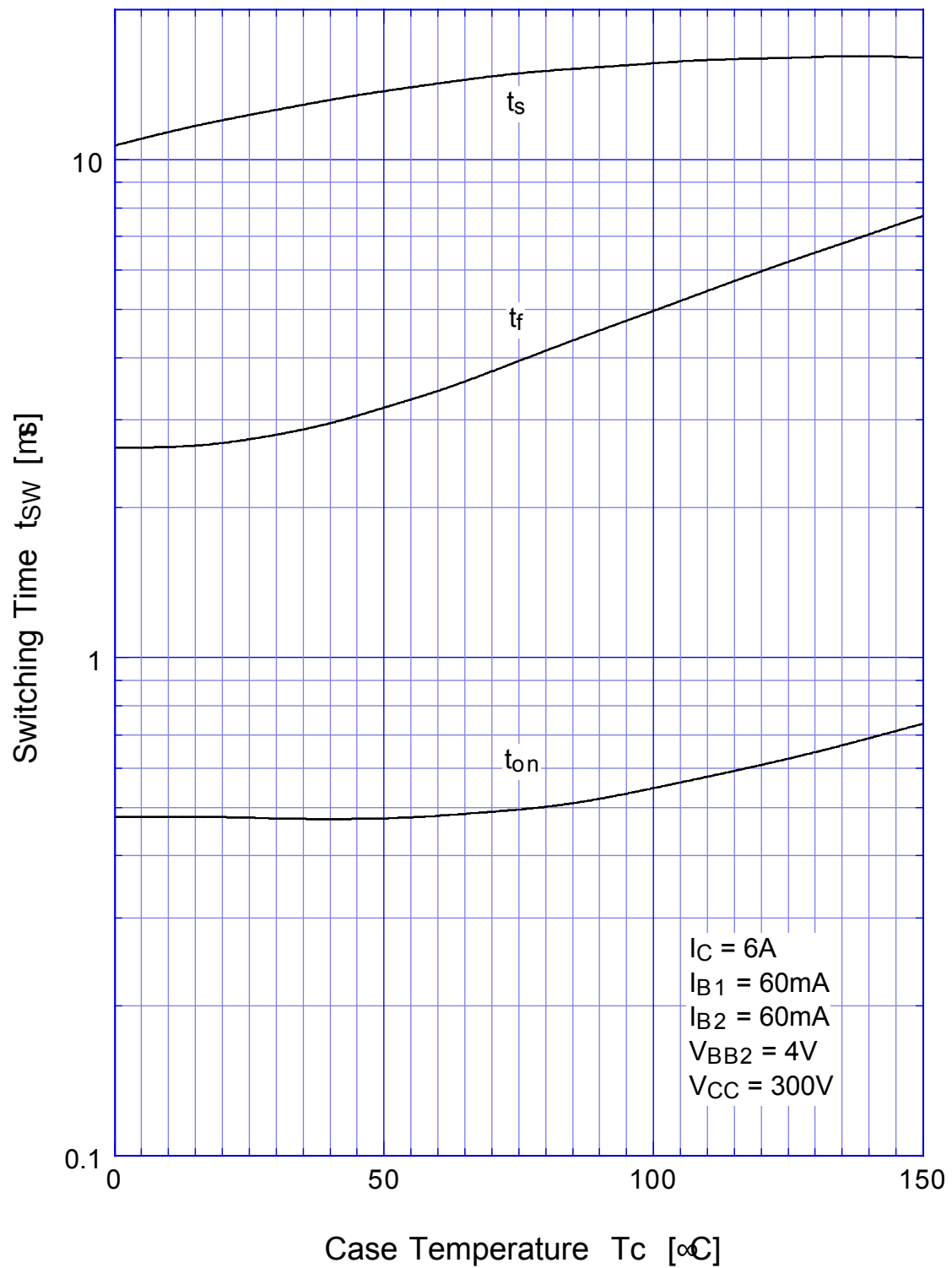
2SD1795

Switching Time - I_C

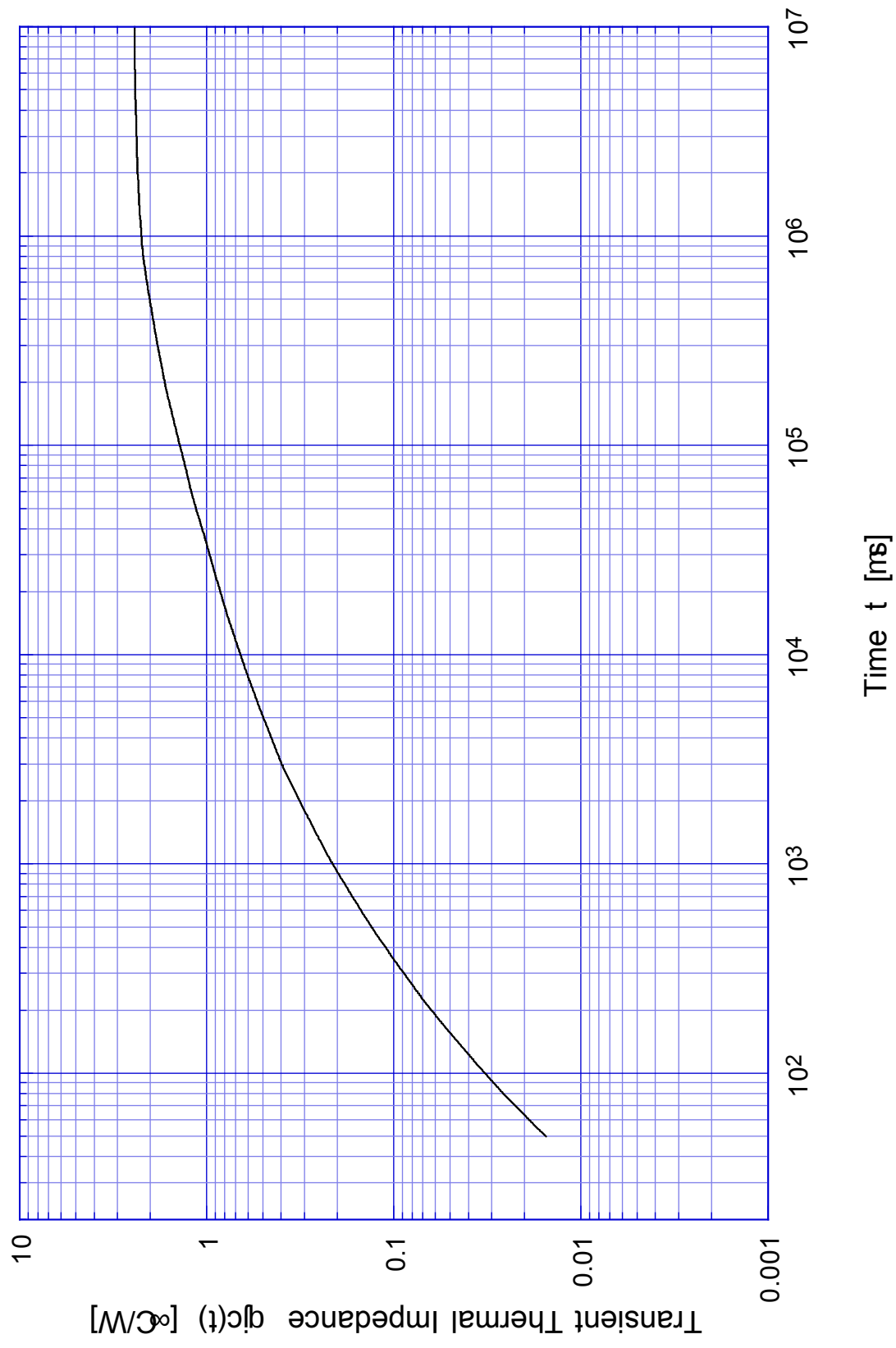


2SD1795

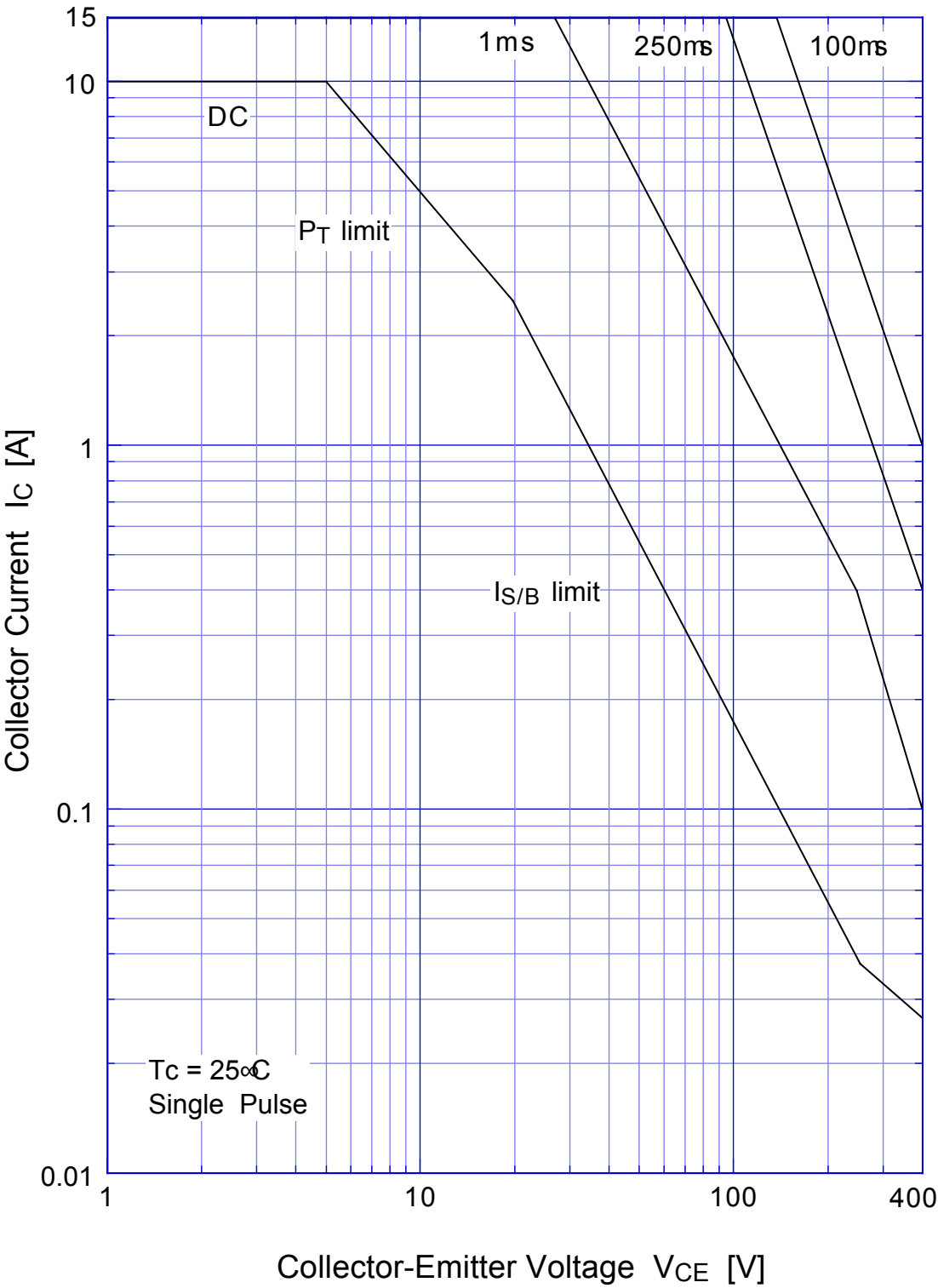
Switching Time - T_c



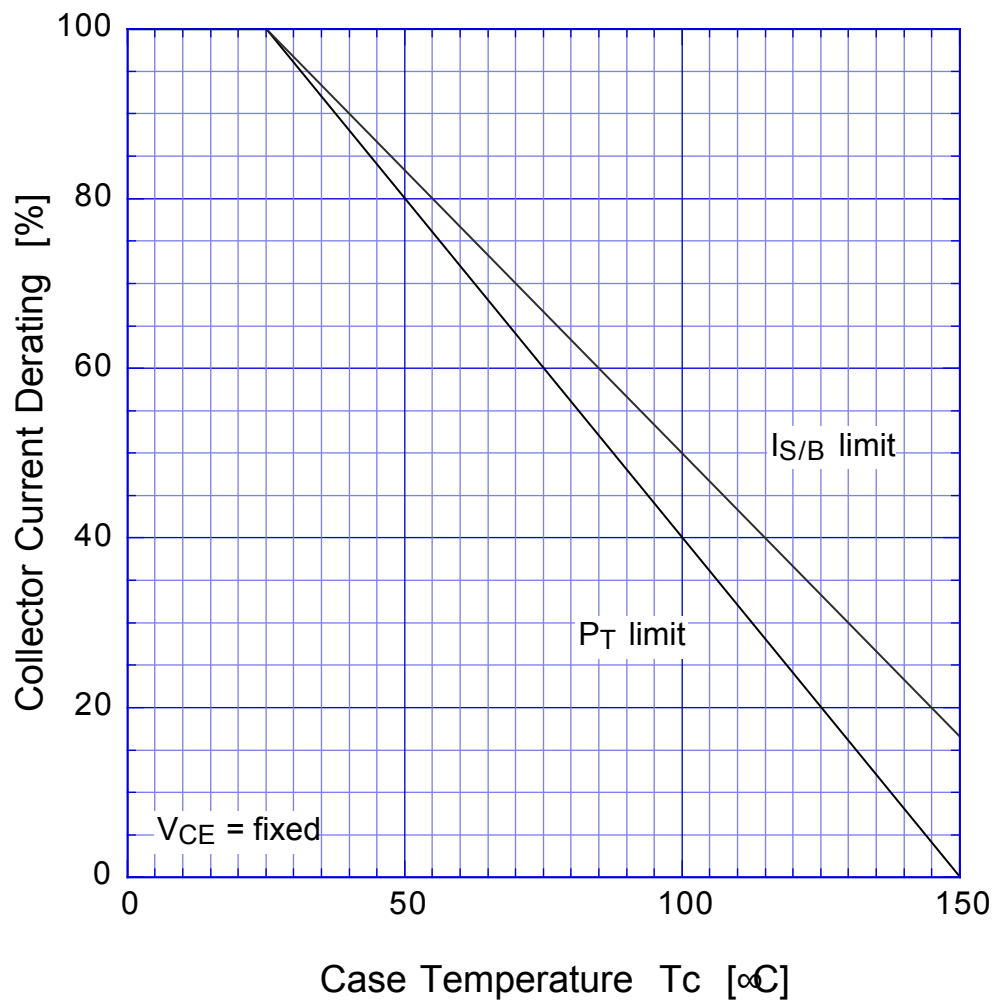
2SD1795 Transient Thermal Impedance



2SD1795 Forward Bias SOA



2SD1795 Collector Current Derating



2SD1795

Reverse Bias SOA

